## The Effect of Aging of ZnO, AZO, and GZO films on the Microstructure and Photoelectric Property

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**Abstract :** RF magnetron sputtering is used on the ceramic targets, each of which contains zinc oxide (ZnO), zinc oxide doped with aluminum (AZO) and zinc oxide doped with gallium (GZO). The XRD analysis showed a preferred orientation along the (002) plane for ZnO, AZO, and GZO films. The AZO film had the best electrical properties; it had the lowest resistivity of  $6.6 \times 10-4$  cm, the best sheet resistance of  $2.2 \times 10-1 \Omega$ /square, and the highest carrier concentration of  $4.3 \times 1020$  cm-3, as compared to the ZnO and GZO films.

Keywords : aging, films, microstructure, photoelectric property

Conference Title : ICCET 2015 : International Conference on Chemical Engineering and Technology

Conference Location : Tokyo, Japan

Conference Dates : May 28-29, 2015